## SPICE Device Model SQM50020EL



Vishay Siliconix

## N-Channel 60 V (D-S) 175 °C MOSFET

### DESCRIPTION

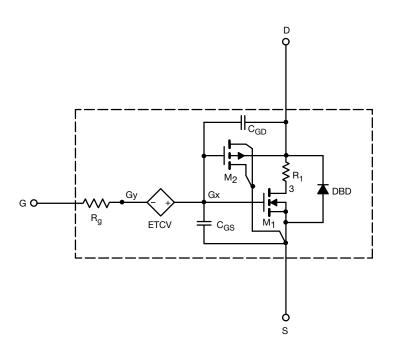
The attached SPICE model describes the typical electrical characteristics of the n-channel vertical DMOS. The sub-circuit model is extracted and optimized over the -55 °C to +125 °C temperature ranges under the pulsed 0 V to 10 V gate drive. The saturated output impedance is best fit at the gate bias near the threshold voltage.

A novel gate-to-drain feedback capacitance network is used to model the gate charge characteristics while avoiding convergence difficulties of the switched  $C_{gd}$  model. All model parameter values are optimized to provide a best fit to the measured electrical data and are not intended as an exact physical interpretation of the device.

### CHARACTERISTICS

- N-Channel Vertical DMOS
- Macro Model (Sub-circuit Model)
- Level 3 MOS
- · Apply for both Linear and Switching Application
- Accurate over the -55 °C to +125 °C Temperature Range
- Model the Gate Charge

### SUBCIRCUIT MODEL SCHEMATIC



#### Note

• This document is intended as a SPICE modeling guideline and does not constitute a commercial product datasheet. Designers should refer to the appropriate datasheet of the same number for guaranteed specification limits.



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<b>SPECIFICATIONS</b> (T <sub>J</sub> = 25 °C, unless otherwise noted)					
PARAMETER	SYMBOL	TEST CONDITIONS	SIMULATED DATA	MEASURED DATA	UNIT
Static					
Gate Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS}=V_{GS},\ I_{D}=250\ \mu A$	2	-	V
Drain-Source On-State Resistance <sup>a</sup>	R <sub>DS(on)</sub>	$V_{GS}$ = 10 V, $I_D$ = 30 A	0.0015	0.0016	Ω
		$V_{GS}$ = 4.5 V, $I_D$ = 20 A	0.0020	0.0020	
Forward Transconductance <sup>a</sup>	g <sub>fs</sub>	$V_{DS} = 15 \text{ V}, \text{ I}_{D} = 30 \text{ A}$	204	164	S
Diode Forward Voltage	V <sub>SD</sub>	I <sub>S</sub> = 80 A	0.87	0.88	V
Dynamic <sup>b</sup>					
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V, f = 1 MHz	10 000	12 060	pF
Output Capacitance	C <sub>oss</sub>		5410	5750	
Reverse Transfer Capacitance	C <sub>rss</sub>		621	860	
Total Gate Charge	Qg	$V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 80 \text{ A}$	144	128	nC
Gate-Source Charge	Q <sub>gs</sub>		33	33	
Gate-Drain Charge	Q <sub>gd</sub>		11	11	

Notes

a. Pulse test; pulse width  $\leq$  300 µs, duty cycle  $\leq$  2 %.

b. Guaranteed by design, not subject to production testing.

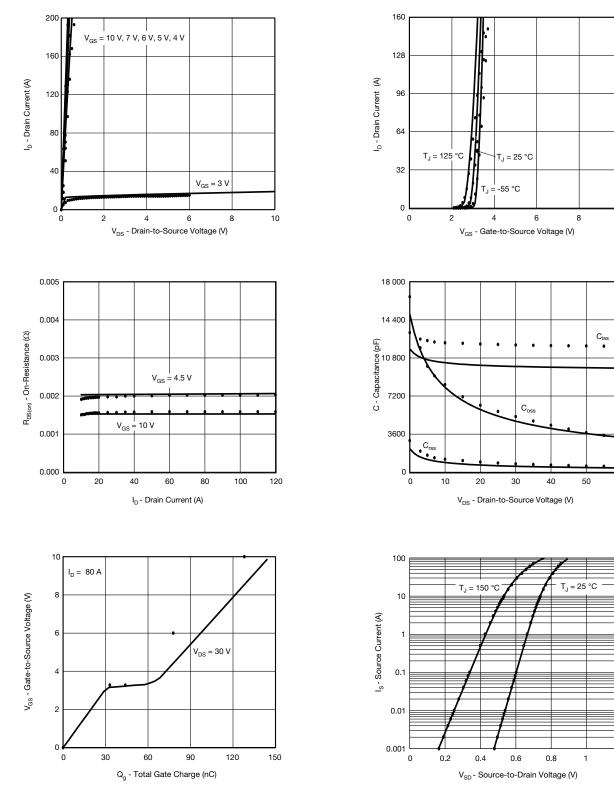


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60

### COMPARISON OF MODEL WITH MEASURED DATA (T\_J = 25 °C, unless otherwise noted)



#### Note

• Dots and squares represent measured data. Copyright: Vishay Intertechnology, Inc.

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